

Hong-Ping

List of Publications by Year in descending order

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Version: 2024-02-01

6
papers

112
citations

1936888

4
h-index

1872312

6
g-index

6
all docs

6
docs citations

6
times ranked

207
citing authors

| # | ARTICLE | IF | CITATIONS |
|---|--|-----|-----------|
| 1 | Systematic Study of the SiO _x Film with Different Stoichiometry by Plasma-Enhanced Atomic Layer Deposition and Its Application in SiO _x /SiO ₂ Super-Lattice. <i>Nanomaterials</i> , 2019, 9, 55. | 1.9 | 52 |
| 2 | Precise control of the microstructural, optical, and electrical properties of ultrathin Ga ₂ O ₃ film through nanomixing with few atom-thick SiO ₂ interlayer <i>via</i> plasma enhanced atomic layer deposition. <i>Journal of Materials Chemistry C</i> , 2018, 6, 12518-12528. | 2.7 | 26 |
| 3 | Measurements of Microstructural, Chemical, Optical, and Electrical Properties of Silicon-Oxygen-Nitrogen Films Prepared by Plasma-Enhanced Atomic Layer Deposition. <i>Nanomaterials</i> , 2018, 8, 1008. | 1.9 | 20 |
| 4 | Enhanced piezoelectric performance of the ZnO/AlN stacked nanofilm nanogenerator grown by atomic layer deposition. <i>APL Materials</i> , 2018, 6, 121109. | 2.2 | 10 |
| 5 | Annealing effect on SiN _x /SiO ₂ superlattice with ultrathin sublayer fabricated using plasma-enhanced atomic layer deposition. <i>Ceramics International</i> , 2022, 48, 22123-22130. | 2.3 | 3 |
| 6 | Formation of quasi-two-dimensional electron gas at the interface of ZnO/Ga ₂ O ₃ heterostructure. <i>AIP Advances</i> , 2021, 11, . | 0.6 | 1 |